

## Ultra-Low Noise Amplifier Tuning Range: 2.0 to 6.0 GHz



#### Features

Reference: 5V/70mA/3.6 GHz

- Gain: 18.5 dB
- Eval Board NF: 0.63 dB
- OP1dB: 18.0 dBm
- 0IP3: 35.0 dBm
- Flexible Bias Voltage and Current
- Process: GaAs pHEMT

#### **Applications**

- Cellular Infrastructure
- Small Cells and Cellular Repeaters
- Distributed Antenna Systems
- C-Band LNA to 6 GHz
- 3.5 GHz CBRS
- TDD-LTE

#### **Product Description**

GRF2073 is a broadband, linear, ultra-low noise amplifier designed for small cell, wireless infrastructure and other high performance RF applications requiring ultra-low NF, high gain and linearity.

This device is a member of a family of pin compatible, ultra low noise devices which cover a wide range of frequency bands with industry leading NF and gain:

GRF2070: 0.1 to 1.5 GHz

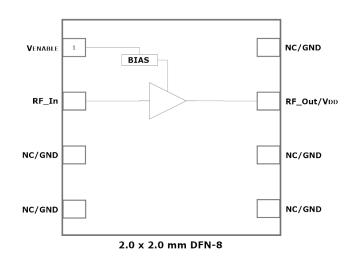
GRF2071: 0.7 to 2.7 GHz

GRF2072: 1.5 to 3.8 GHz

GRF2073: 2.0 to 6.0 GHz

GRF2074: 1.0 to 6.0 GHz (next-gen process)

Consult with the GRF applications engineering team for application notes, custom tuning/evaluation board data and device s-parameters.



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## **Absolute Ratings:**

Parameter	Symbol	Min.	Max.	Unit
Supply Voltage	Vdd	0	6.0	V
RF Input Power: (Load VSWR < 2:1; V <sub>D</sub> : 5.0 volts)	P <sub>IN MAX</sub>		23	dBm
Operating Temperature (Package Heat Sink)	T <sub>AMB</sub>	-40	105	°C
Maximum Channel Temperature (MTTF > 10^6 Hours)	Тмах		170	°C
Maximum Dissipated Power	P <sub>DISS MAX</sub>		500	mW
Electrostatic Discharge:				
Charged Device Model:	CDM	1500		V
Human Body Model:	HBM	500		V
Storage:				
Storage Temperature	Tstg	-65	150	°C
Moisture Sensitivity Level	MSL		1	



Caution! ESD Sensitive Device

Exceeding Absolute Maximum Rating conditions may cause permanent damage to the device.

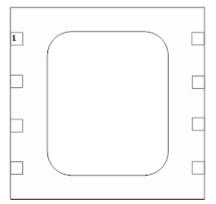
Note: For manufacturing information, see the Guerrilla-RF.com website for the following document located on the GRF2073 landing page: Manufacturing Note—MN-001 Product Tape and Reel, Solderability and Package Outline Specification.

#### Link to manufacturing note





Pin Out (Top View)



### **Pin Assignments:**

Pin	Name	Description	Note
1	VENABLE	Enable Voltage Input	$\label{eq:Venable} \begin{array}{l} V_{\text{ENABLE}} \text{ and series resistor set } Iddq. \ Venable < \texttt{=0.2} \ volts \ disables \ device. \ On \\ -die \ pull-down \ resistor \ will \ turn \ the \ part \ off \ if \ this \ node \ is \ allowed \ to \ float. \end{array}$
2	RF_In	RF Input	External match must provide DC block
3	NC/GND	No Connect or Ground	No internal connection to die
4	NC/GND	No Connect or Ground	No internal connection to die
5	NC/GND	No Connect or Ground	No internal connection to die
6	NC/GND	No Connect or Ground	No internal connection to die
7	RF_Out/VDD	RF Output	Provide device VDD via external bias inductor
8	NC/GND	No Connect or Ground	No internal connection to die
PKG BASE	GND	Ground	Provides DC and RF ground for LNA, as well as thermal heat sink. Recom- mend multiple 8 mil vias beneath the package for optimal RF and thermal performance. Refer to evaluation board top layer graphic on schematic page.





## **Nominal Operating Parameters:**

Parameter	Symbol	Specification			Unit	Condition	
Falameter	Symbol	Min.	Тур.	Max.	Unit	Condition	
Gain Mode (Venable high)						V <sub>DD</sub> = 5.0 V, T <sub>A</sub> = 25 °C	
Test Frequency	FTEST		3.6		GHz	3.4 to 3.8 GHz Tune	
Gain	S21	17.5	18.5		dB		
Evaluation Board Noise Figure	NF		0.65	0.85	dB	Evaluation Board SMA to SMA	
Output 3rd Order Intercept Point	0IP3		35.0		dBm	+3 dBm Pout per tone at 2 MHz Spacing (3599 and 3601 MHz)	
Output 1dB Compression Point	OP1dB	16.5	18.0		dBm		
Switching Rise Time	T <sub>RISE</sub>		300		ns		
Switching Fall Time	T <sub>FALL</sub>		300		ns		
Supply Current	ldd		70		mA		
Enable Current	IENABLE		3.5		mA		
Thermal Data							
Thermal Resistance (measured via IR scan)	Θјс		60		°C/W	On standard evaluation board	
Channel Temperature @ +85 C Reference (Package Heat Sink)	TCHANNEL		106 (See note)		٥C	Vdd: 5.0 V; Iddq: 70 mA; No RF; Pdiss: 350 mW	

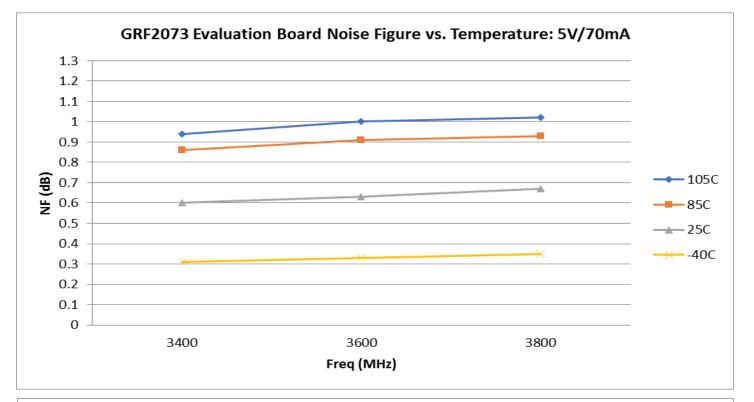
Note: MTTF >10^6 hours for TCHANNEL < =170 degrees C.

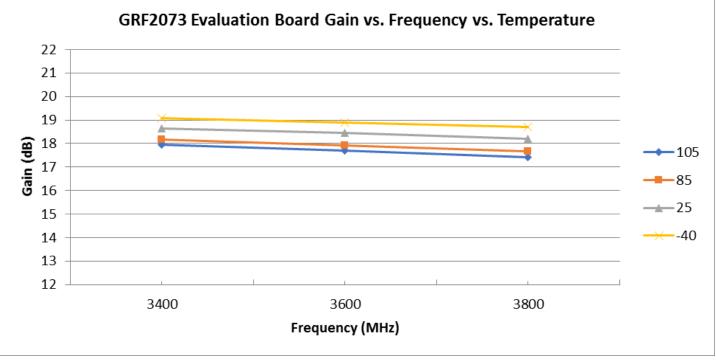
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#### **GRF2073 Evaluation Board Measured Data:**



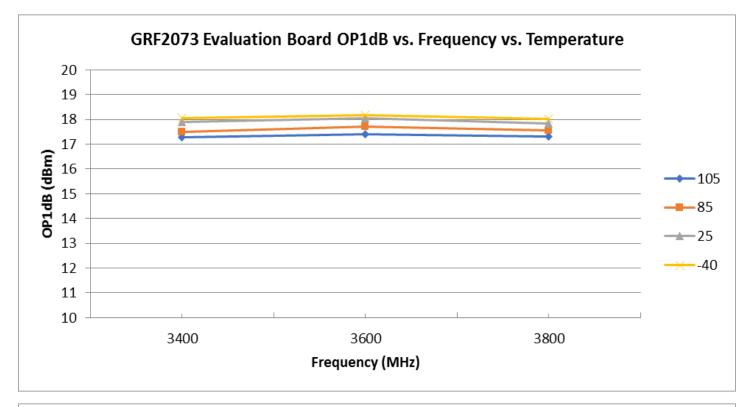


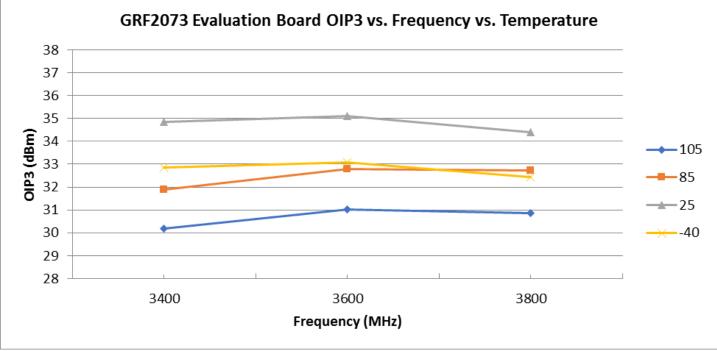
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**GRF2073 Evaluation Board Measured Data:** 



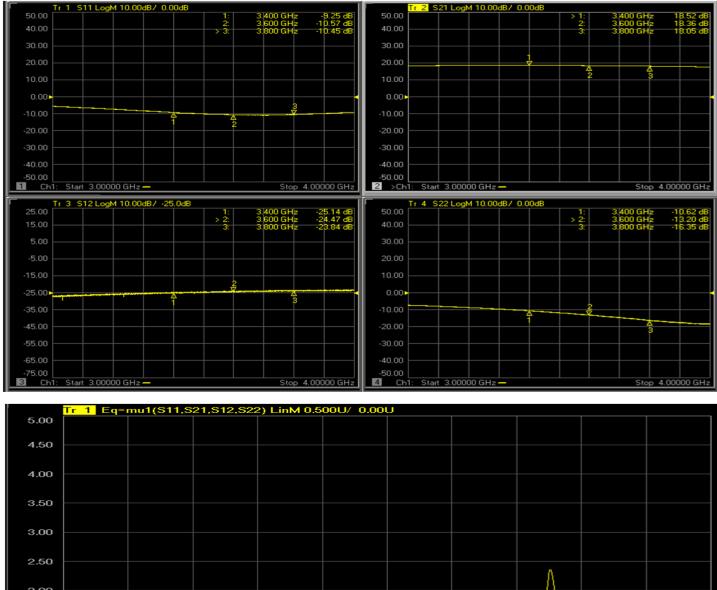


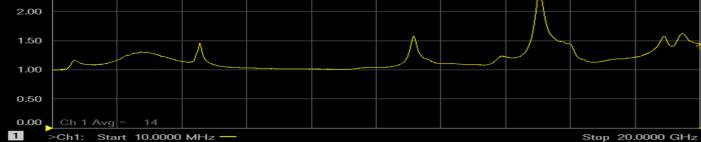
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## Ultra-Low Noise Amplifier Tuning Range: 2.0 to 6.0 GHz

### GRF2073 Evaluation Board S-Pars and Stability Mu Factor: (3.4 to 3.8 GHz Match)



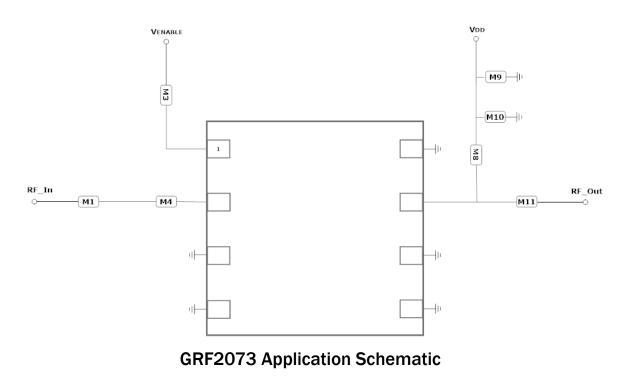


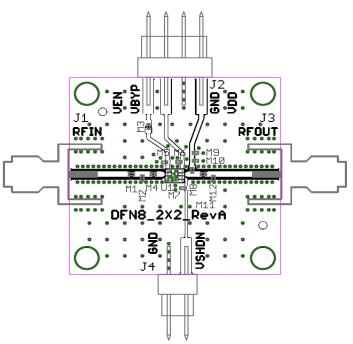
#### Note: Mu factor >= 1.0 implies unconditional stability.

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**GRF2073** 







### **GRF2073 EVB Assembly Drawing**

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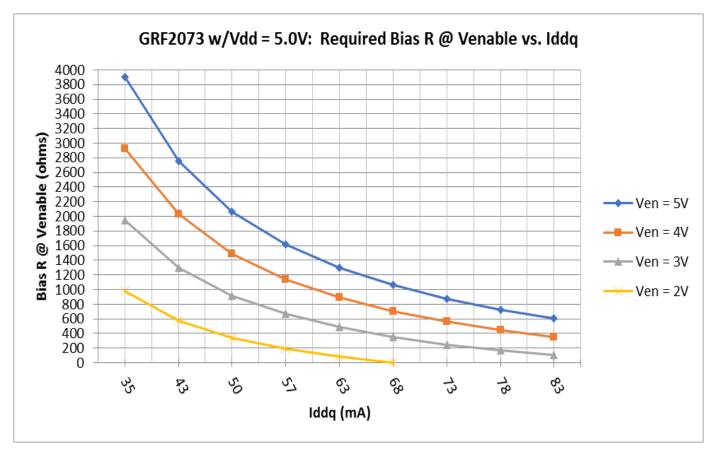


## Ultra-Low Noise Amplifier Tuning Range: 2.0 to 6.0 GHz

Component	Туре	Manufacturer	Family	Value	Package Size	Substitution
M1	Capacitor	Murata	GJM	1.2 pF	0402	Ok (high Q)
M3	Resistor	Various	5%	Sets Iddq	0402	ok
M4	Resistor	Various	_	0 Ohm	0402	ok
M8	Inductor	Murata	LQP/LQG	1.8 nH	0402	ok
M9	Capacitor	Murata	GRM	0.1 uF	0402	ok
M10	Capacitor	Murata	GRM	100 pF	0402	ok
M11	Capacitor	Murata	GJM	5.1 pF	0402	ok
Evaluation Board	DFN8_2x2_RevA	_	_	_	_	_

#### GRF2073 Standard Evaluation Board BOM: (3.4 to 3.8 GHz Tune)

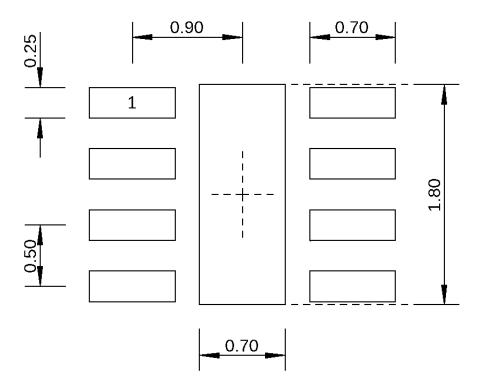
#### **GRF2073 Bias Resistor Selection Curves:**



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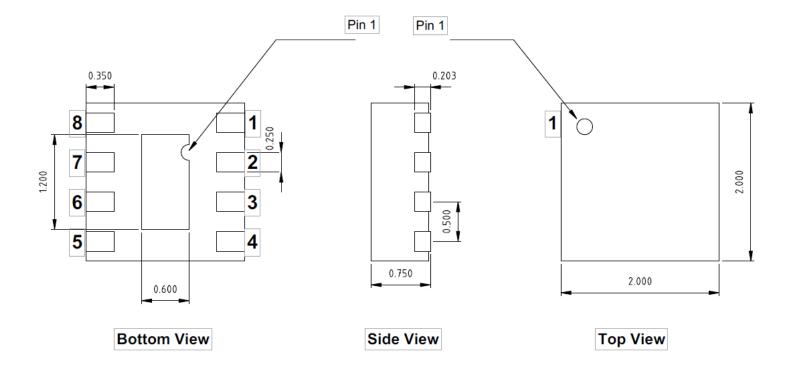
**Dimensions in millimeters** 

2.0 mm DFN-8 Suggested PCB Footprint (Top View)

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**GRF2073** 





2.0 x 2.0 DFN-8 Package Dimensions (mm)

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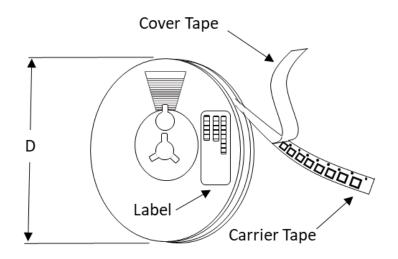


## Ultra-Low Noise Amplifier Tuning Range: 2.0 to 6.0 GHz

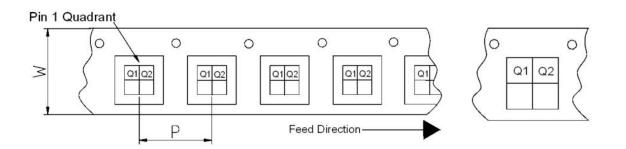
#### Tape and Reel Information:

Guerrilla RF's Tape and Reel specification complies with the Electronics Industries Association (EIA) standards for 'Embossed Carrier Tape of Surface Mount Components for Automatic Handling". Reference EIA-481. See the table on the following page for Tape and Reel specifications along with units per reel.

Devices are loaded with pins down into the carrier pocket with protective cover tape, wound into a plastic reel. Each reel will be packaged in a cardboard box. There will be product labels on the reel, the protective ESD bag and the outside surface of the box.



Tape and Reel Packaging with Reel Diameter Noted (D)



Carrier Tape Width (W), Pitch (P), Feed Direction and Pin 1 Quadrant Information

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#### Tape and Reel Specification and Device Package Information Table

Package			Carrier Tape			Reel		
Туре	Dimensions (mm)	Leads	Weight (mg)	Width (W) (mm)	Pocket Pitch (P) (mm)	Pin 1 Quad- rant	Diameter (D) (inches)	Units per Reel
QFN	2.0 x 2.0 x 0.50	12	7	8	4	Q1	7	2500
QFN	3.0 x 3.0 x 0.85	16	24	12	8	Q1	7	1500
DFN	1.5 x 1.5 x 0.45	6	4	8	4	Q1	7	2500
DFN	2.0 x 2.0 x 0.75	8	12	8	4	Q1	7	2500
LFM	3.5 x 3.5 x 0.75	See note	TBD	12	8	Q2	7	1500
LFM	4.0 x 4.0 x 0.75	See note	TBD	12	8	Q2	7	1500

Note: Lead count may vary. Reference applicable product data sheet



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Data Sheet Release Status:	Notes
Advance	S-parameter and NF data based on EM simulations for the fully packaged device using foundry supplied transistor s-parameters. Linearity estimates based on de- vice size, bias condition and experience with related devices.
Preliminary	All data based on evaluation board measurements in the Guerrilla RF Applications Lab.
Released	All data based on device qualification data. Typically, this data is nearly identical to the data found in the preliminary version. Max and min values for key RF parameters are included.

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